

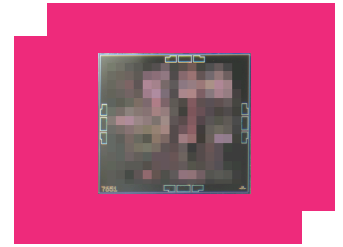
# MM1-0115HCH-3

## GaAs MMIC Double Balanced Mixer

### DEVICE OVERVIEW

#### General Description

MM1-0115H is a GaAs MMIC double balanced mixer that features excellent conversion loss, superior isolations, and spurious performance across a broad 1-15 GHz bandwidth. The MM1-0115H works well as both an up and down converter through the Ku band with an IF response from DC to 2.5 GHz. The MM1-0115H is recommended for frequency conversion applications that require high linearity. It is available as both wire bondable die and as a connectorized module.



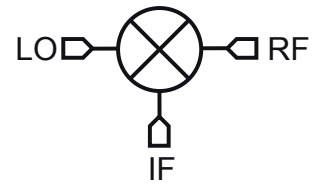
#### Features

- High LO to RF isolation
- Up or down conversion
- Broadband, high linearity frequency conversion
- Two identical IF ports available on chip for ease of layout

#### Applications

- Test and Measurement Equipment
- SATCOM
- Electronic Warfare
- Radar

#### Functional Block Diagram



#### Part Ordering Options

Part Number	Description	Package	Connectors	Green Status	Product Lifecycle	Export Classification
<u>MM1-0115HS</u>	GaAs MMIC Double Balanced Mixer	S	<u>Standard</u>	REACH RoHS	Released	EAR99
MM1-0115HCH-3	GaAs MMIC Double Balanced Mixer	CH	-	REACH RoHS	Released	EAR99

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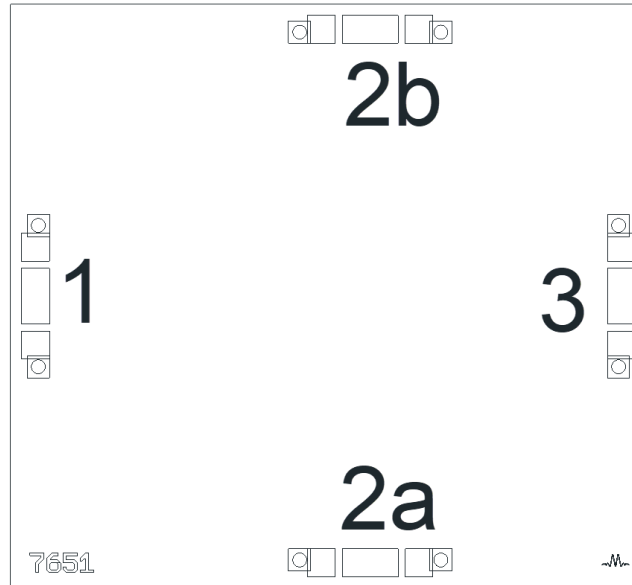
**Revision History**

Revision Code	Revision Date	Comment
-	2022-05-01	Datasheet Initial Release

## Port Configuration and Functions

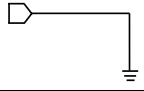
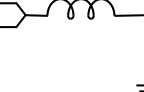
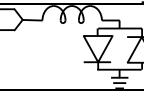

### Port Diagram

A top-down view of the MM1-0115H's CH package outline drawing is shown below. The MM1-0115H has the input and output ports given in Port Functions. The MM1-0115H can be used in either an up or down conversion. For configuration A, input the LO into port 1, use port 3 for the RF, and port 2a or 2b for the IF. For configuration B, input the LO into port 3, use port 1 for the RF, and port 2a or 2b for the IF.

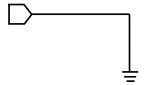
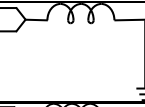

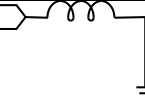


## Port Functions

### Configuration A

Port	Function	Description	Equivalent Circuit for Package
GND	Ground	CH package ground path is provided through the substrate and ground bond pads	
Port 1	LO	Port 1 is DC short for the CH and S packages.	
Port 2	IF	Port 2a and Port 2b are diode connected for the CH and S package.	
Port 3	RF	Port 3 is DC short for the CH and S packages.	

**Configuration B**

Port	Function	Description	Equivalent Circuit for Package
GND	Ground	CH package ground path is provided through the substrate and ground bond pads.	
Port 1	RF	Port 1 is DC short for the CH and S packages	
Port 2	IF	Port 2a and Port 2b are diode connected for the CH and S package.	
Port 3	LO	Port 3 is DC short for the CH and S packages.	

## Specifications

### Absolute Maximum Ratings

The Absolute Maximum Ratings indicate limits beyond which damage may occur to the device. If these limits are exceeded, the device may be inoperable or have a reduced lifetime.

Parameter	Maximum Rating	Unit
Maximum Operating Temperature	100	°C
Maximum Storage Temperature	125	°C
Minimum Operating Temperature	-55	°C
Minimum Storage Temperature	-65	°C
Port 1 DC Current	30	mA
Port 2 DC Current	30	mA
Port 3 DC Current	30	mA
Power Handling, at any Port	33	dBm

### Package Information

Parameter	Details	Rating
ESD	250 to < 500 Volts	HBM Class 1A
Dimensions	-	2.28x2.09mm

### Recommended Operating Conditions

The Recommended Operating Conditions indicate the limits, inside which the device should be operated, to guarantee the performance given in Electrical Specifications. Operating outside these limits may not necessarily cause damage to the device, but the performance may degrade outside the limits of the electrical specifications. For limits, above which damage may occur, see Absolute Maximum Ratings.

Parameter	Min	Nominal	Max	Unit
Ambient Temperature	-55	25	100	°C
LO Input Power	13	17	21	dBm

### Sequencing Requirements

There is no requirement to apply power to the ports in a specific order. However, it is recommended to provide a 50Ω termination to each port before applying power. This is a passive diode mixer that requires no DC bias.

## Electrical Specifications

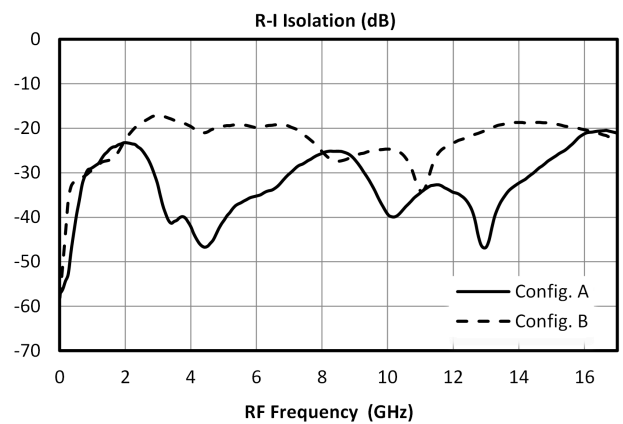
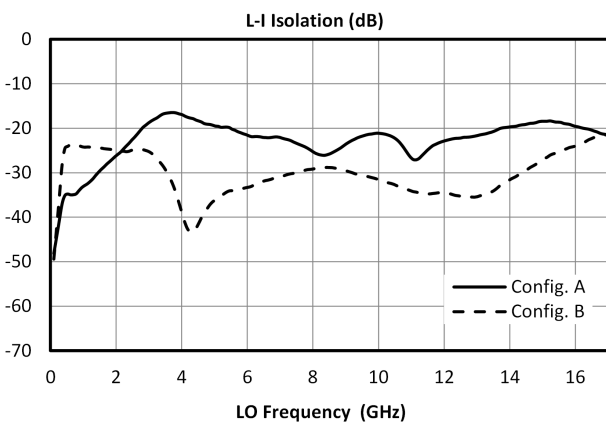
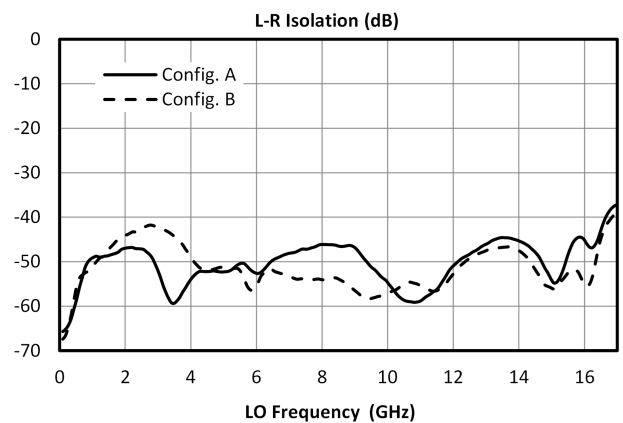
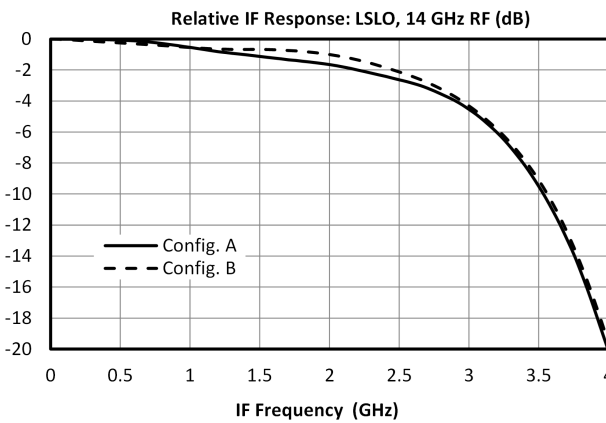
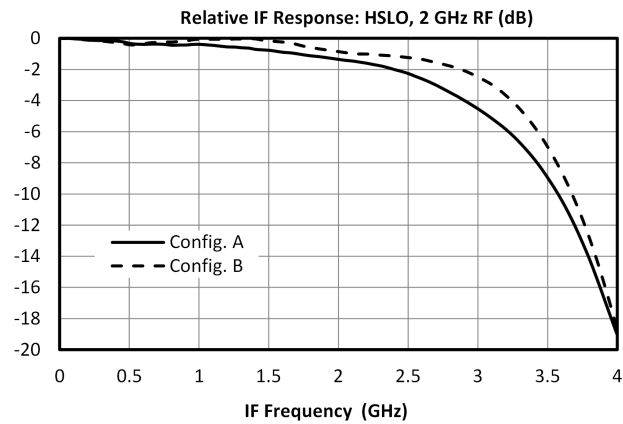
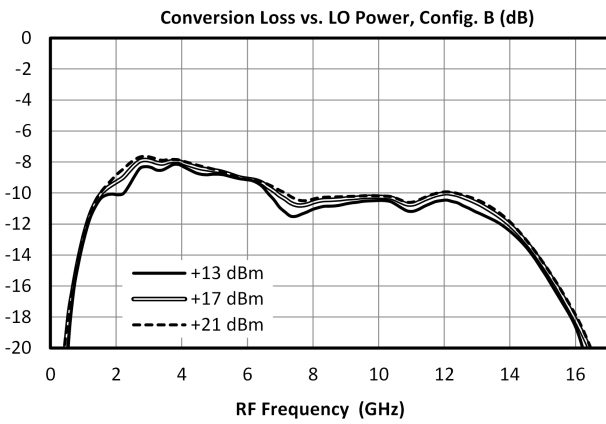
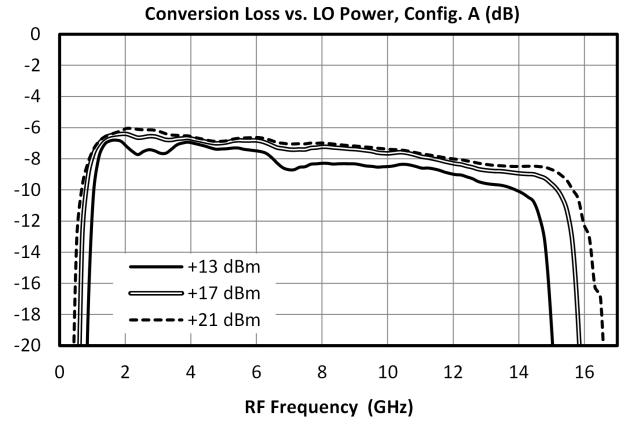
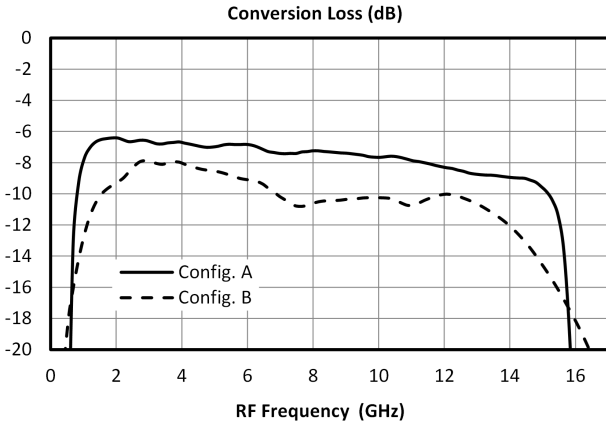
The electrical specifications apply at TA=+25°C in a 50Ω system. Typical data shown is for the connectorized S package mixer used in the forward direction with a +17 dBm sine wave input. Min and Max limits apply only to our connectorized units and are guaranteed at TA=+25°C. All bare die are 100% DC tested and visually inspected.

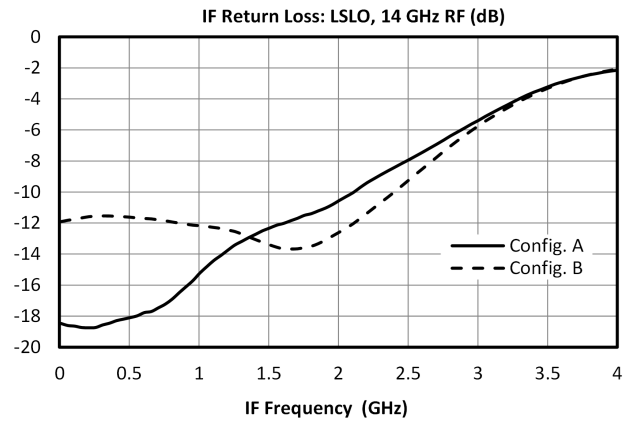
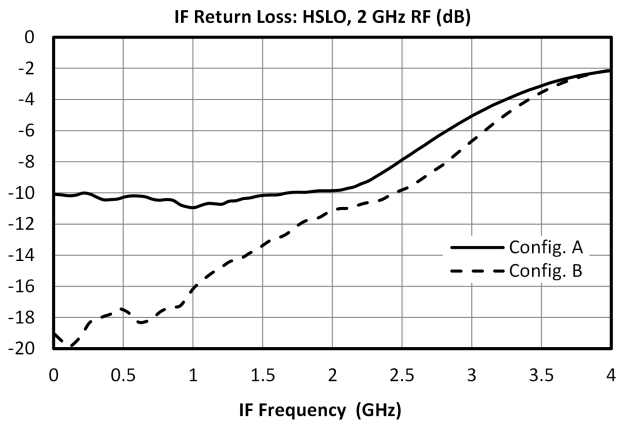
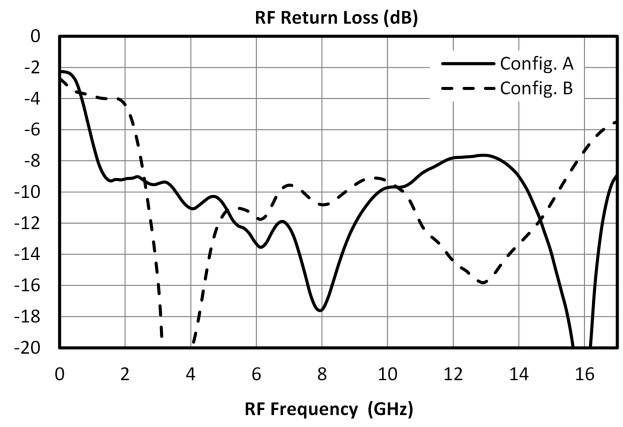
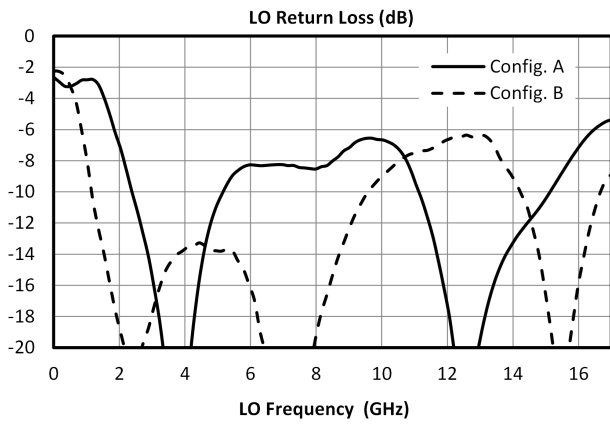
Parameter	Port Configuration	Test Conditions	Min	Typ	Max	Unit
Conversion Loss <sup>1</sup>	A	RF/LO = 1 - 15GHz I = 0.2 - 2.5 GHz	-	8.5	-	dB
Conversion Loss <sup>2</sup>	A	RF/LO = 1 - 15 GHz I = DC - 0.2 GHz	-	7.5	12.5	dB
Input 1 dB Gain Compression Point (P1dB)	A	-	-	10	-	dBm
Input IP3	A	RF/LO = 1 - 15 GHz I = DC - 0.2 GHz	-	21	-	dBm
Isolation, LO to IF	A	IF/LO = 1 - 15 GHz	-	22	-	dB
Isolation, LO to RF	A	RF/LO = 1 - 15 GHz	-	50	-	dB
Isolation, RF to IF	A	RF/IF = 1 - 15 GHz	-	34	-	dB
Noise Figure <sup>3</sup>	A	RF/LO = 1 - 15 GHz I = DC - 0.2 GHz	-	7.5	-	dB
Conversion Loss <sup>4</sup>	B	RF/LO = 1 - 15GHz I = 0.2 - 2.5 GHz	-	11	-	dB
Conversion Loss <sup>5</sup>	B	RF/LO = 1 - 15 GHz I = DC - 0.2 GHz	-	10	17.5	dB
Input 1 dB Gain Compression Point (P1dB)	B	-	-	13	-	dBm
Input IP3	B	RF/LO = 1 - 15 GHz I = DC - 0.2 GHz	-	24	-	dBm
Isolation, LO to IF	B	IF/LO = 1 - 15 GHz	-	32	-	dB
Isolation, LO to RF	B	RF/LO = 1 - 15 GHz	-	51	-	dB
Isolation, RF to IF	B	RF/IF = 1 - 15 GHz	-	22	-	dB
Noise Figure <sup>6</sup>	B	RF/LO = 1 - 15 GHz I = DC - 0.2 GHz	-	10	-	dB
IF Frequency Range	-	-	0	-	2.5	GHz
LO Frequency Range	-	-	1	-	15	GHz
RF Frequency Range	-	-	1	-	15	GHz

[1][2][4][5] Measured as a down converter to a fixed 91MHz IF.

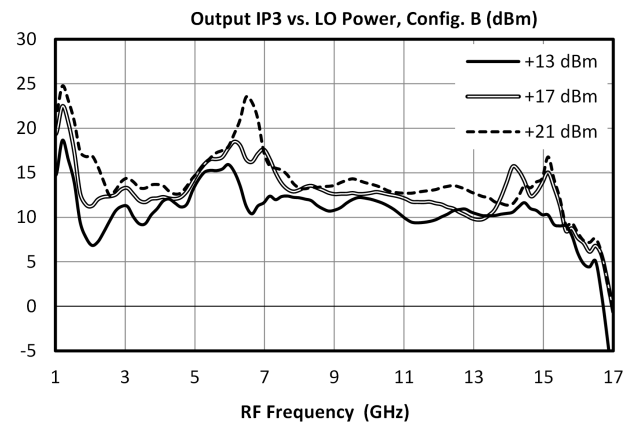
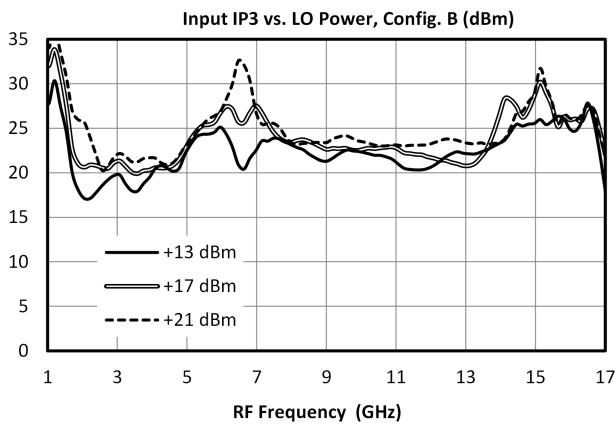
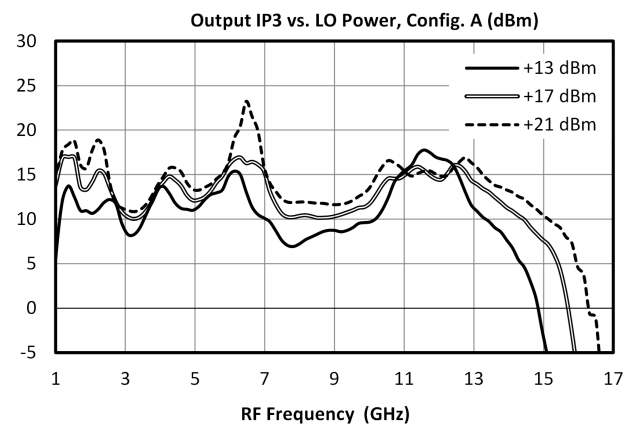
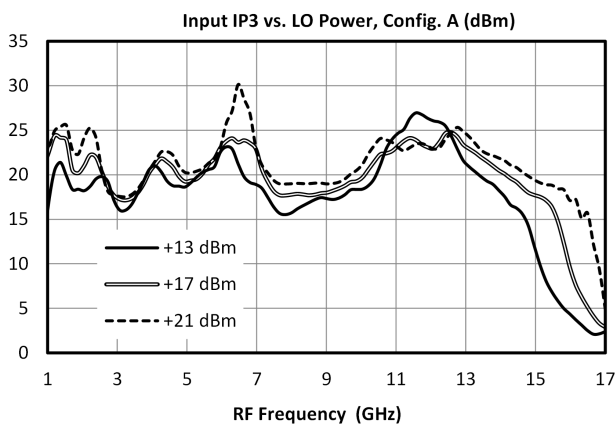
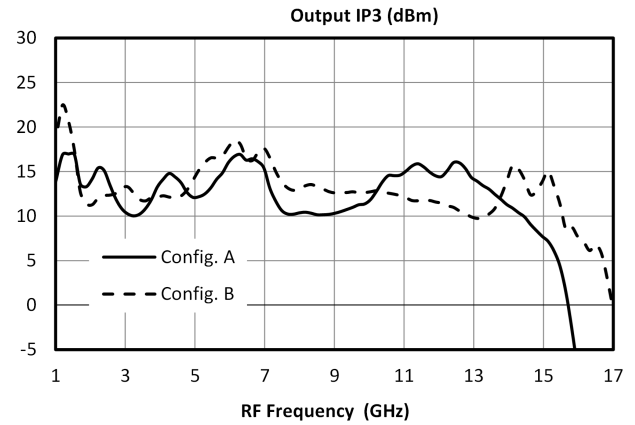
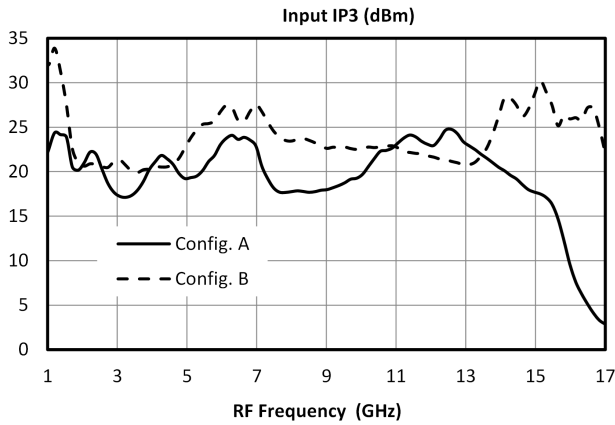
[3][6] Mixer Noise Figure typically measures within 0.5 dB of conversion loss for IF frequencies greater than 5 MHz.

**Typical Performance Plots**

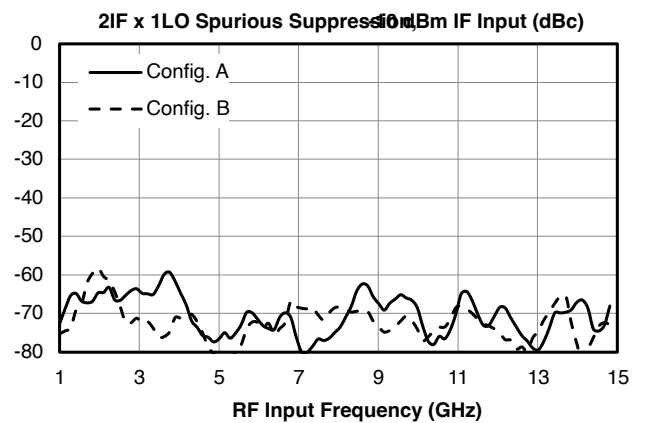
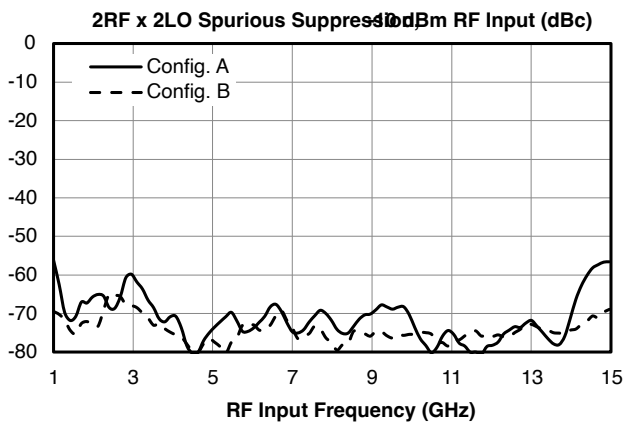
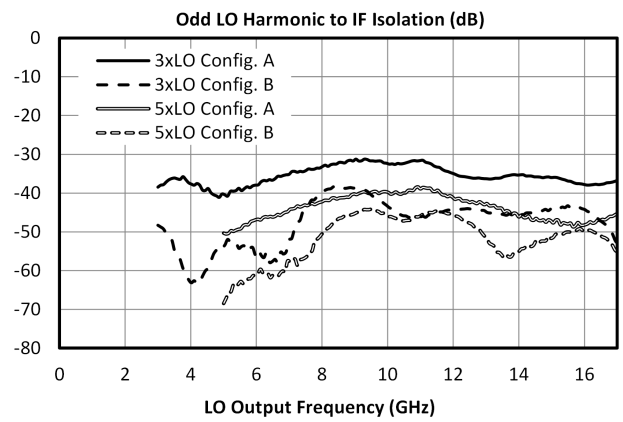
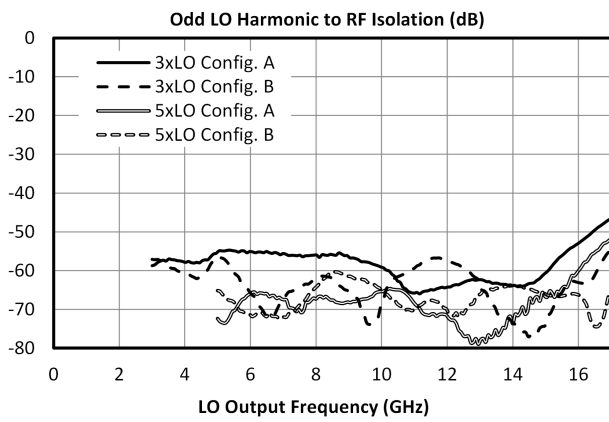
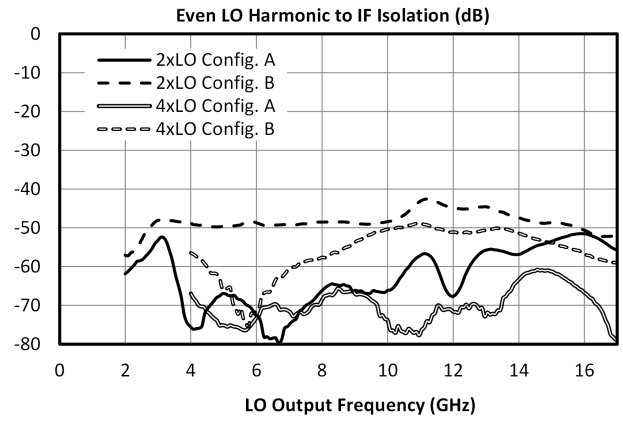
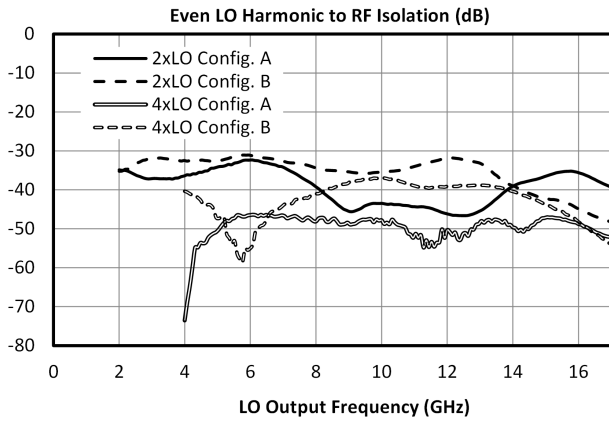




**Typical Performance Plots: IP3**

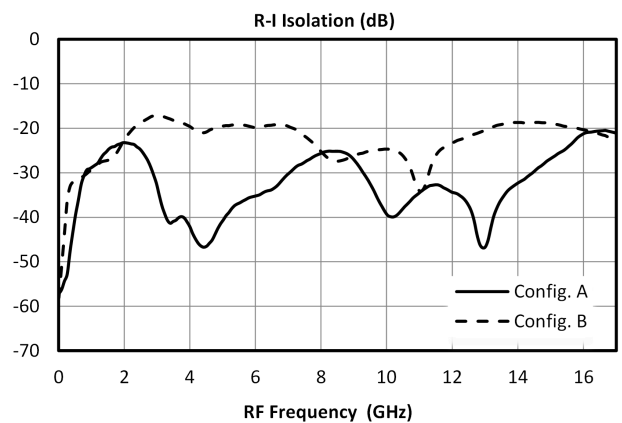
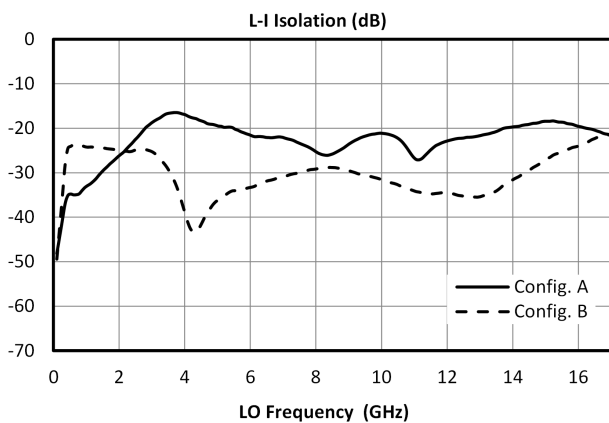
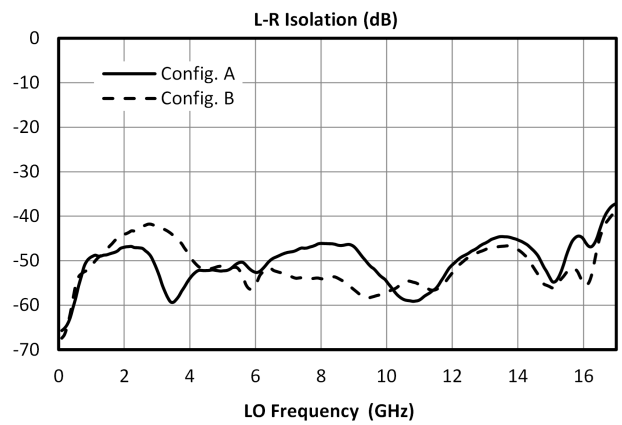
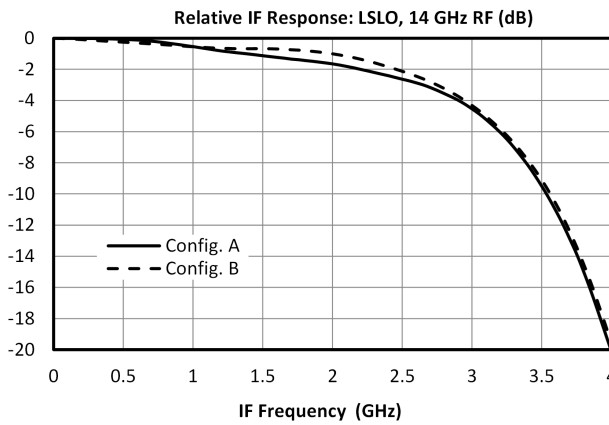
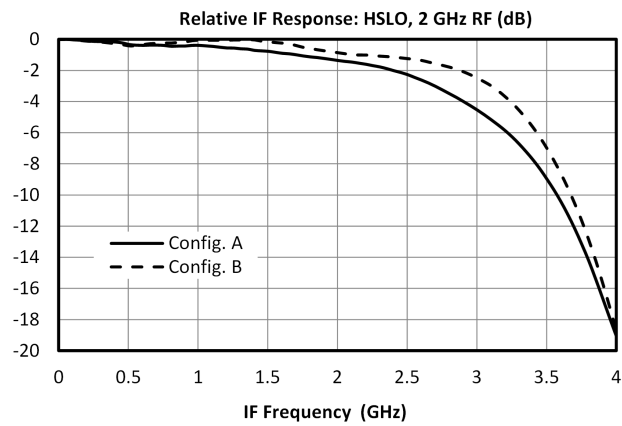
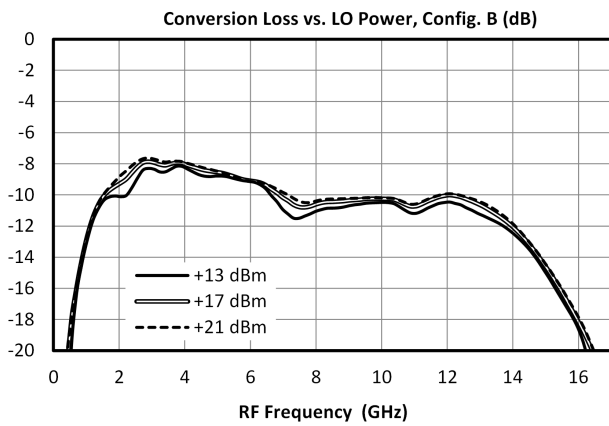
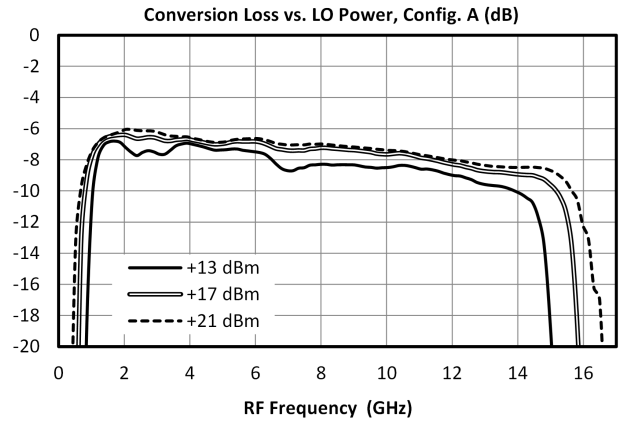
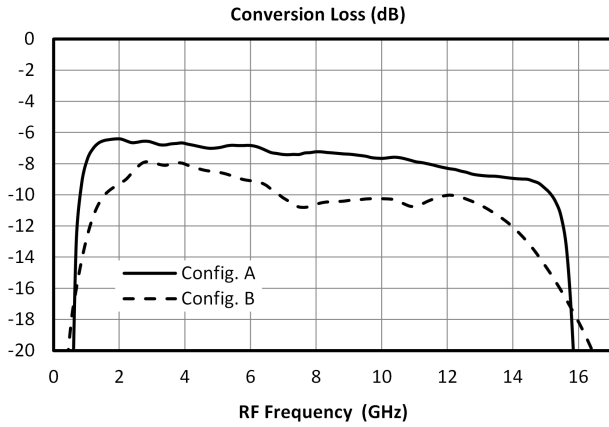


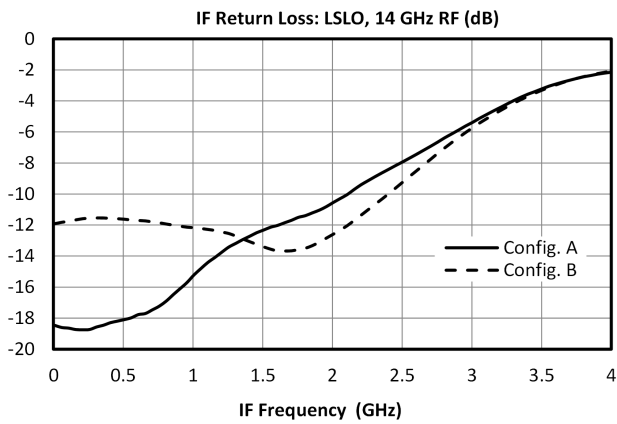
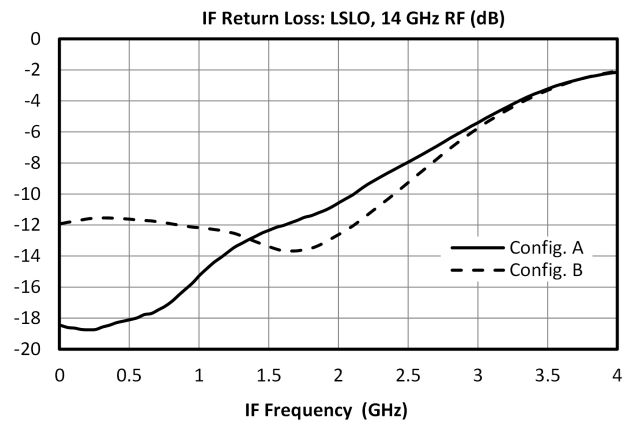
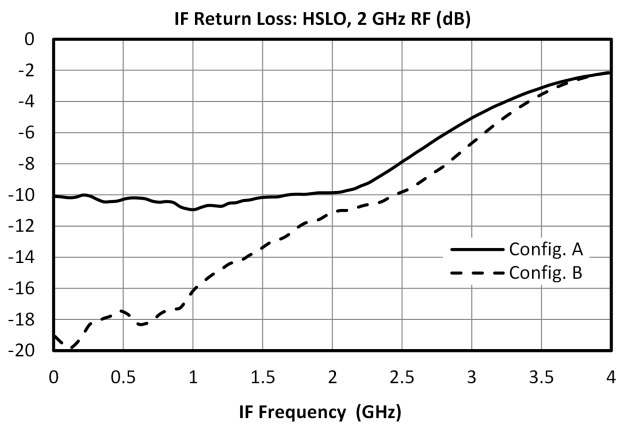
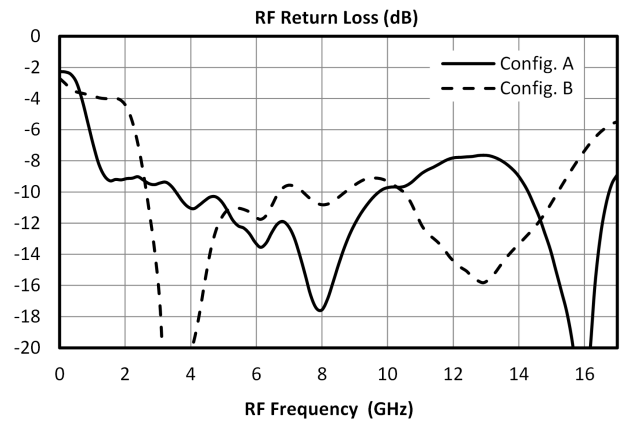
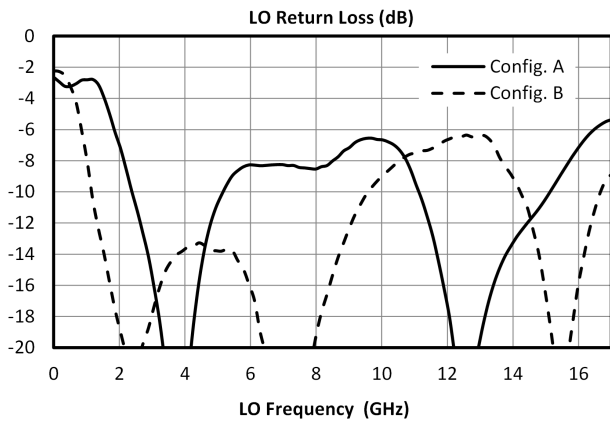
**Typical Performance Plots: LO Harmonic Isolation**



**MM1-0115HS - Typical Performance Plots**

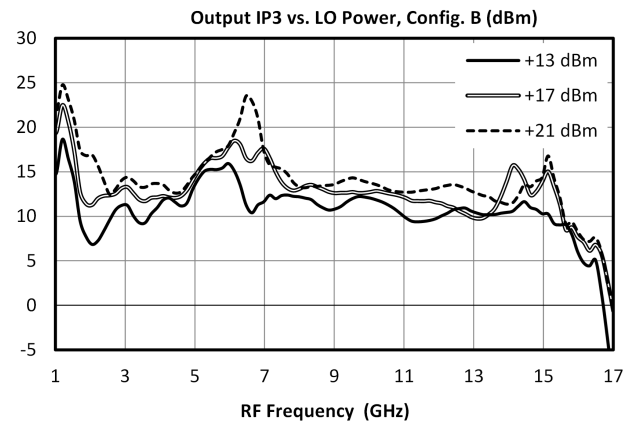
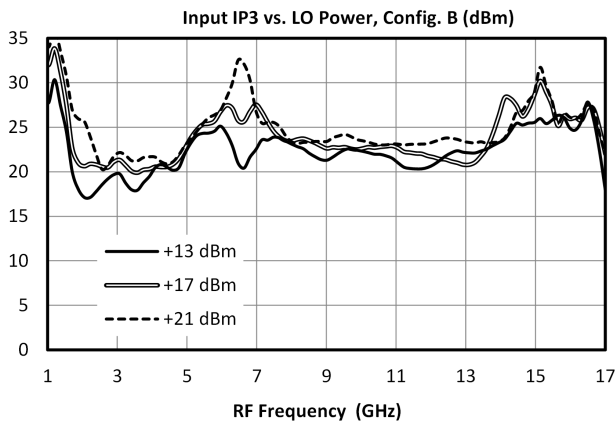
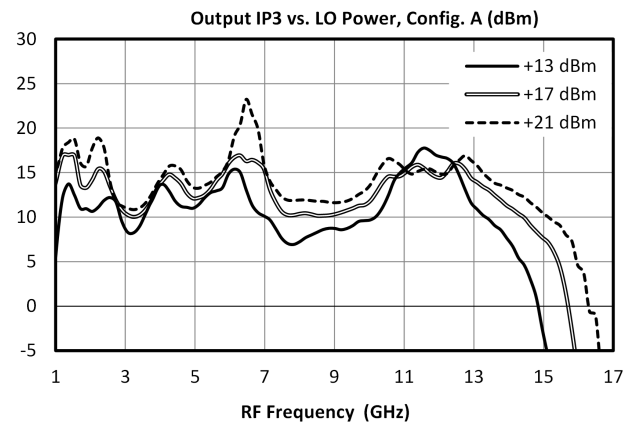
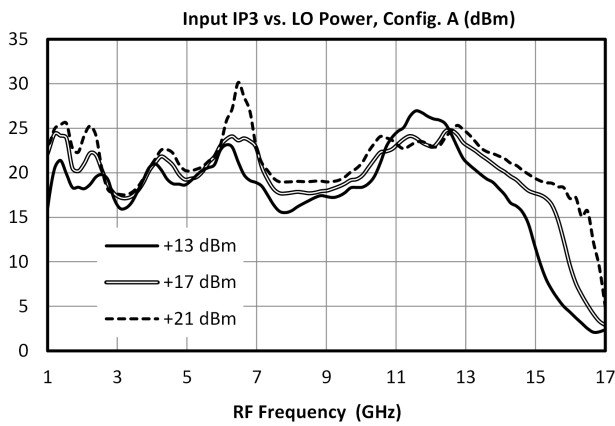
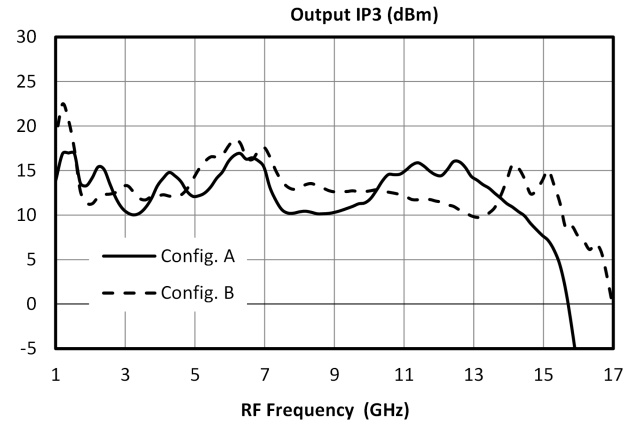
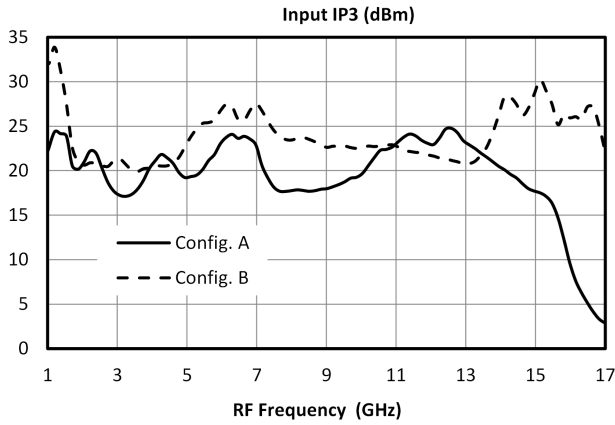
Performance plots for the connectorized module are shown for measurements where directly probed measurements of the die are unavailable. Note that the following measurements include losses from connectors and microstrip traces.





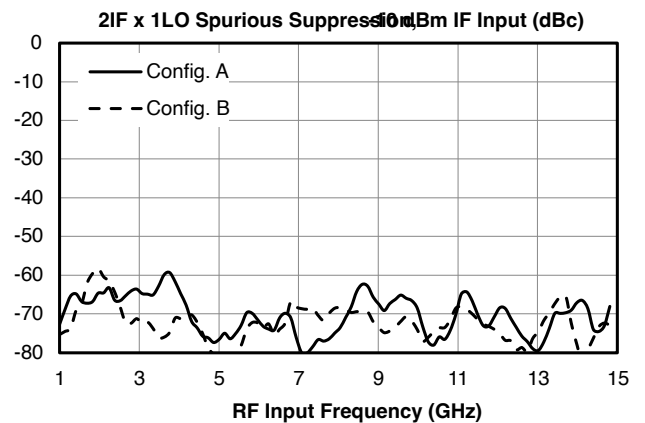
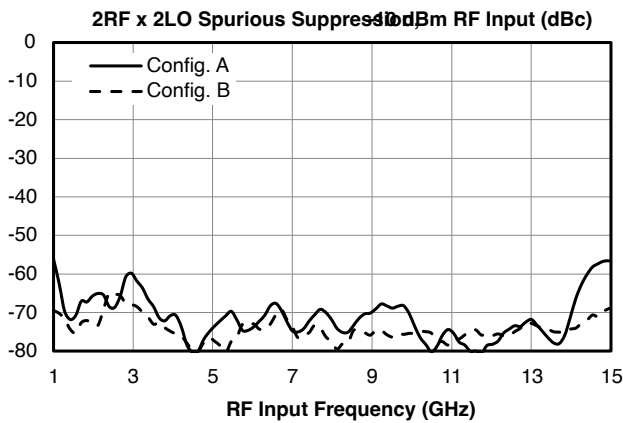
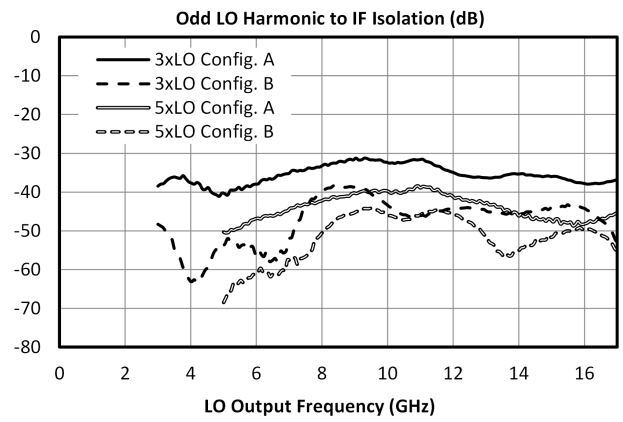
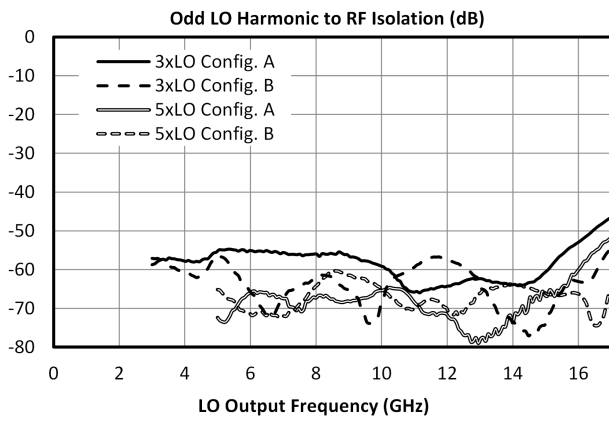
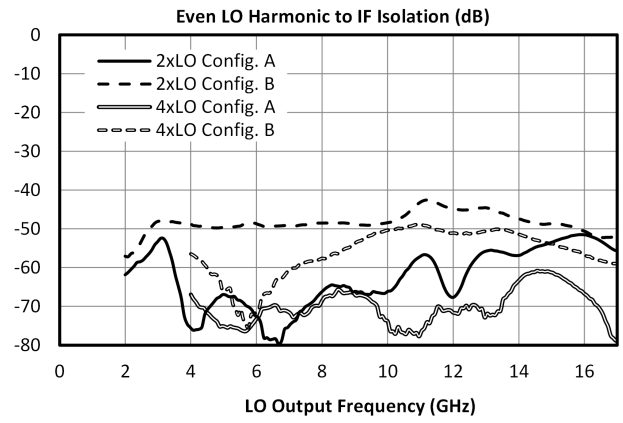
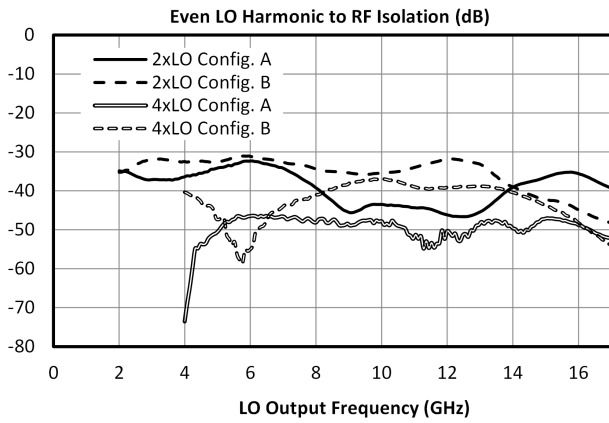
**MM1-0115HS - Typical Performance Plots: IP3**

Performance plots for the connectorized module are shown for measurements where directly probed measurements of the die are unavailable. Note that the following measurements include losses from connectors and microstrip traces.



**MM1-0115HS - Typical Performance Plots: LO Harmonic Isolation**

Performance plots for the connectorized module are shown for measurements where directly probed measurements of the die are unavailable. Note that the following measurements include losses from connectors and microstrip traces.



## Spur Table

### Typical Spurious Performance: Down-Conversion

Typical spurious data is provided by selecting RF and LO frequencies ( $\pm m \cdot LO \pm n \cdot RF$ ) up to 25GHz. The mixer is swept across the full spurious band and the mean is calculated. The numbers shown in the table below are for a -10 dBm RF input. Spurious suppression is scaled for different RF power levels by  $(n-1)$ , where “n” is the RF spur order. For example, the 2RF x 2LO spur is 72 dBc for a -10 dBm input, so a -20 dBm RF input creates a spur that is  $(2-1) \times (-10 \text{ dB})$  lower, or 82 dBc. Data is shown for the frequency plan in Typical Performance.  $mLO \times nRF$  plots can be found in section 3.6.2 Typical Performance Plots: LO Harmonic Isolation.

**Typical Down-conversion spurious suppression (dBc): Config A (B)**

-10 dBm RF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xRF	19 (12)	Reference	26 (30)	12 (10)	35 (41)	21 (19)
2xRF	74 (77)	53 (55)	72 (78)	55 (60)	72 (77)	58 (59)
3xRF	85 (98)	62 (69)	76 (91)	75 (72)	79 (77)	65 (78)
4xRF	N/A	98 (109)	109 (117)	100 (109)	109 (115)	99 (110)
5xRF	N/A	113 (123)	119 (128)	114 (126)	120 (132)	117 (127)

**Typical Spurious Performance: Up-Conversion**

Typical spurious data is taken by mixing an input within the IF band, with LO frequencies ( $\pm m \cdot LO \pm n \cdot IF$ ), to create a spurious output within the RF output band. The mixer is swept across the full spurious output band and the mean is calculated. The numbers shown in the table below are for a -10 dBm IF input. Spurious suppression is scaled for different IF input power levels by (n-1), where “n” is the IF spur order. For example, the 2IFx1LO spur is typically 43 dBc for a -10 dBm input with a sine-wave LO, so a -20 dBm IF input creates a spur that is (2-1) x (-10 dB) lower, or 53 dBc. Data is shown for the frequency plan in Typical Performance.

**Typical Up-conversion spurious suppression (dBc): Config A (B)**

-10 dBm IF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xIF	20 (12)	Reference	26 (31)	11 (10)	34 (43)	21 (17)
2xIF	52 (59)	43 (43)	60 (59)	54 (53)	53 (53)	60 (60)
3xIF	79 (66)	50 (50)	73 (76)	58 (57)	73 (79)	60 (59)
4xIF	97 (96)	74 (75)	92 (96)	84 (84)	85 (90)	88 (88)
5xIF	117 (106)	85 (86)	110 (115)	96 (98)	109 (111)	93 (100)

## Die Mounting Recommendations

### Mounting and Bonding Recommendations

Marki MMICs should be attached directly to a ground plane with conductive epoxy. The ground plane electrical impedance should be as low as practically possible. This will prevent resonances and permit the best possible electrical performance. Datasheet performance is only guaranteed in an environment with a low electrical impedance ground.

**Mounting** - To epoxy the chip, apply a minimum amount of conductive epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip. Cure epoxy according to manufacturer instructions.

**Wire Bonding** - Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

**Circuit Considerations** – 50 Ω transmission lines should be used for all high frequency connections in and out of the chip. Wirebonds should be kept as short as possible, with multiple wirebonds recommended for higher frequency connections to reduce parasitic inductance. In circumstances where the chip more than .001” thinner than the substrate, a heat spreading spacer tab is optional to further reduce bondwire length and parasitic inductance.

## Handling Precautions

### General Handling

Chips should be handled with care using tweezers or a vacuum collet. Users should take precautions to protect chips from direct human contact that can deposit contaminants, like perspiration and skin oils on any of the chip's surfaces.

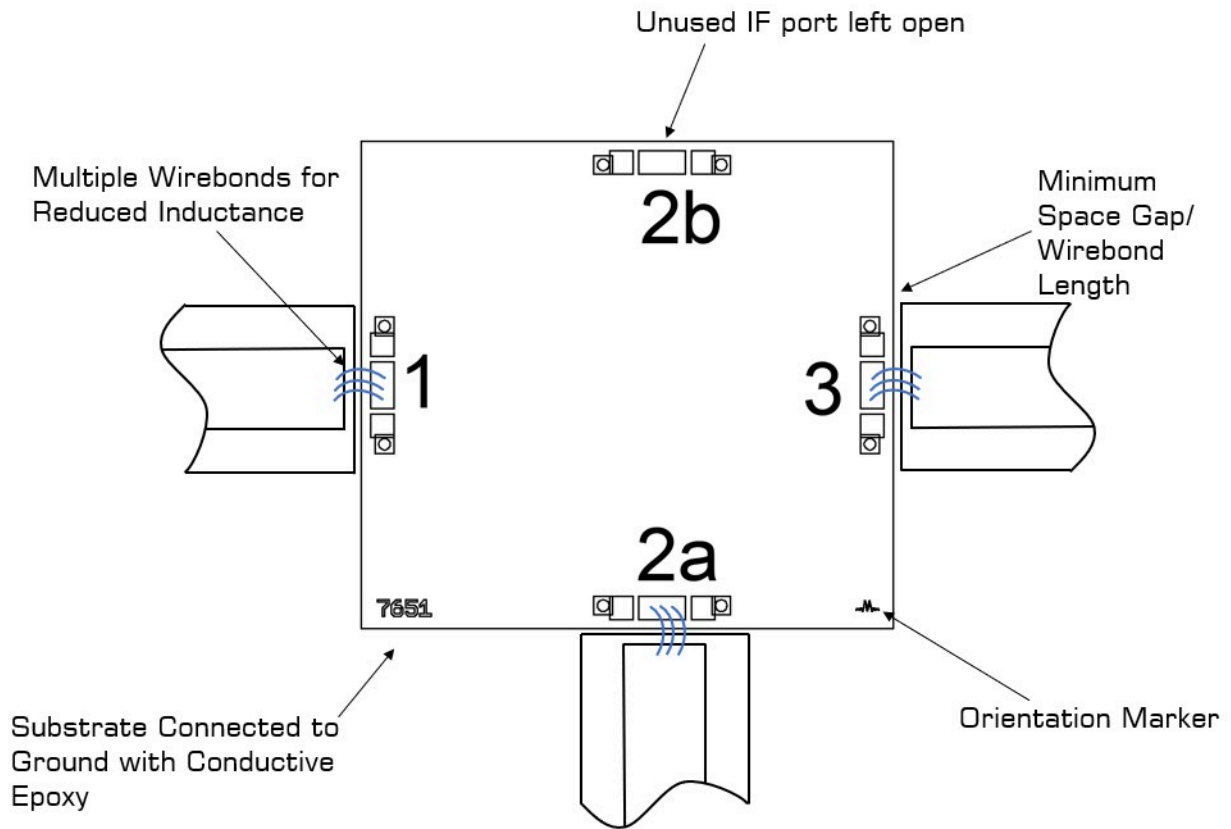
### Static Sensitivity

GaAs MMIC devices are sensitive to ESD and should be handled, assembled, tested, and transported only in static protected environments.

**Cleaning and Storage:** Do not attempt to clean the chip with a liquid cleaning system or expose the bare chips to liquid. Once the ESD sensitive bags the chips are stored in are opened, chips should be stored in a dry nitrogen atmosphere.

**Bonding Diagram**

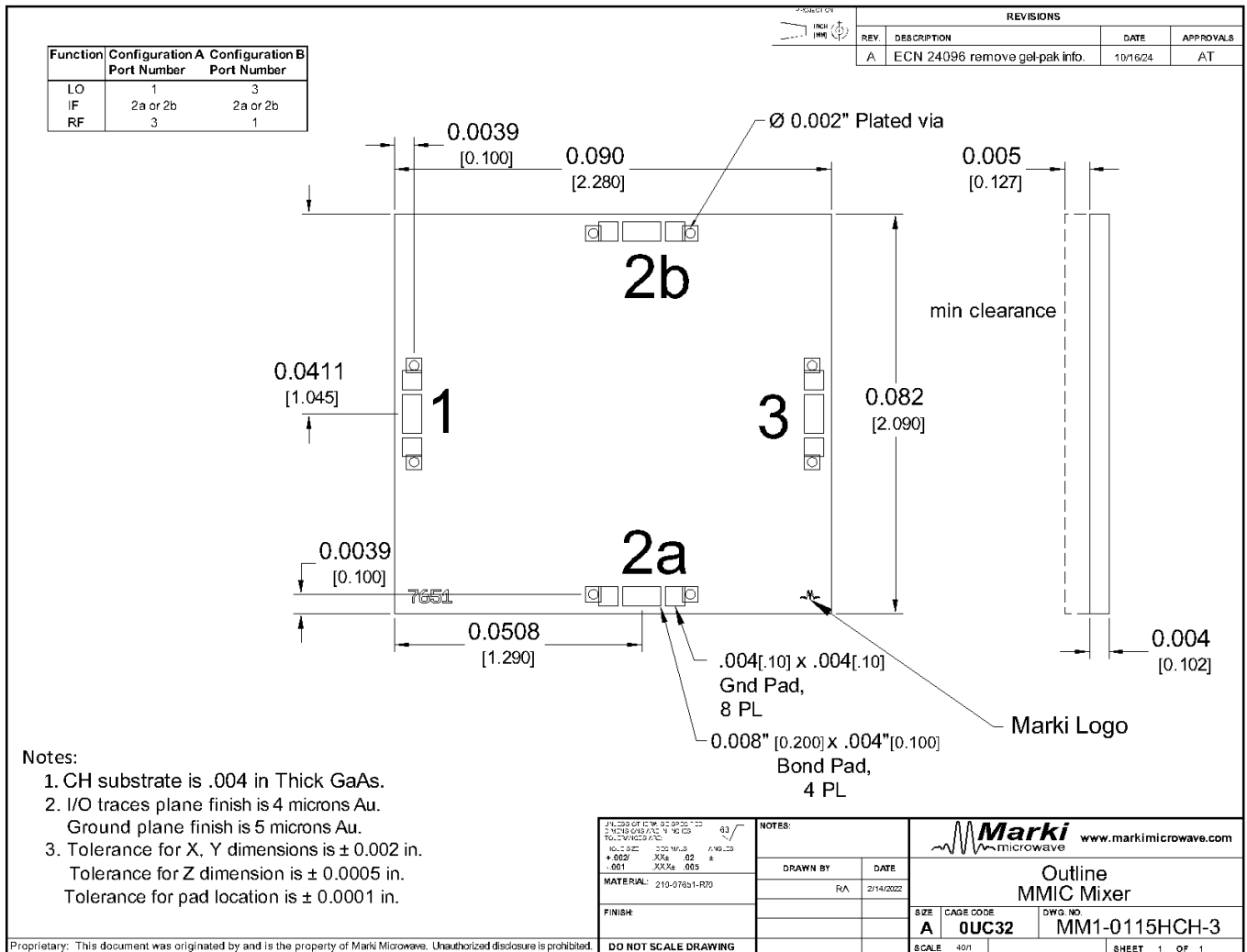
Either port 2a or port 2b can be used as an IF port with identical performance. Unused IF port must remain open for normal operation.



### Mechanical Data

### Outline Drawing

Download : [Outline 2D Drawing](#)



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